

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3687	257/77,369,371.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/08 05:54
L2	1834	438/172,217,285.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/08 06:02
L3	1729	438/93,105,197.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/08 06:10
L4	529	438/299.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/08 06:10

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	4	(stressed near2 layer and silicon adj1 carbide).CLM.	US-PGPUB	OR	OFF	2005/09/08 06:15
L2	4	(stressed near2 layer and silicon and carbide).CLM.	US-PGPUB	OR	OFF	2005/09/08 06:15
L3	0	(stressed adj1 semiconductor adj1 layer and silicon and carbide).CLM.	US-PGPUB	OR	OFF	2005/09/08 06:15
L4	11	(stressed and silicon and carbide).CLM.	US-PGPUB	OR	OFF	2005/09/08 06:15